Therm al conductivity of the therm oelectric layered cobalt oxides m easured by the Harm an method

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In-plane therm alconductivity of the therm oelectric layered cobalt oxides has been m easured using the H arm an m ethod, in which therm alconductivity is obtained from temperature gradient induced by applied current. We have found that the charge reservoir block (the block other than the CoO $_2$ block) dominates the thermal conduction, where a nano-block integration concept is elective for material design. We have further found that the thermal conductivity shows a small but nite in-plane anisotropy between a and baxes, which can be ascribed to the m is t structure.

Therm oelectric m aterials have recently attracted a renewed interest as a energy-conversion m aterial in harm ony with our environments. They are characterized by the dimensionless gure of merit ZT = S^2T= , where S, and are the therm opower, resistivity and therm alconductivity at temperature T, respectively. In other words, the therm oelectric m aterial is a material that shows large therm opower, low resistivity and low therm alconductivity sin ultanously.

O xides were regarded as unsuitable for therm oelectrics, but the layered cobalt oxides have been extensively investigated as a prom ising therm oelectric material since the discovery of a large therm opower in NaCo₂O₄ (Na_{0.5}CoO₂) [1, 2]. Soon after, the related layered cobalt oxides Bi₂ xPb_xSr₂Co₂O_y [3, 4], Ca₃Co₄O₉ [5, 6, 7], Ca₂ (Cu,Co)₂Co₄O₉ [8] T Sr_2 Co₂O_y [9], and (Pb,Co)Sr₂Co₂O_y [10] have been synthesized and identied. They share the hexagonal CdI₂-type CoO₂ block as a common unit as shown in Fig. 1, and show good there

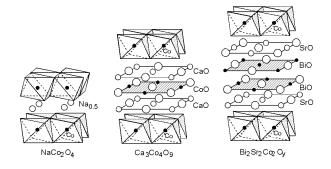


FIG.1: Crystal structure of the layered cobalt oxides.

m oelectricity of Z T > 1 above 1000 K [11, 12, 13]. This m eans that their therm oelectric perform ance is comparable with that of the conventional therm oelectric materials such as PbTe and Si₁ $_{\rm x}$ Ge_x.

Single crystals of the therm oelectric layered cobalt oxides are very thin and small, and the heat loss is too serious to measure precisely. There are only a few reports on measurement of single crystals, all of which were done above room temperature [11, 12, 13]. Fujita et al. [11] found that the in-plane therm al conductivity of a N a_x C oO $_2$ single crystal was 200 m W /cm K at room tem perature, and decreased rapidly at high tem peratures. This is highly inconsistent with the other layered cobalt oxides [12, 13] and the polycrystalline NaC o_2O_4 [14, 15], which needs cross-checking by other technique. We have succeeded in measuring in-plane of single crystals of N a_x C oO $_2$, B i_2 $_x$ P b_x S r_2 C o_2 O $_y$ and C a_3 C o_4 O $_9$ by the Harm an method. Here we will report on the experim ental details of the Harm an method and the in-plane of the layered cobalt oxides below room temperature.

 $B_{12}\ _xP_{b_x}Sr_2C_{o_2}O_y$ single crystals were grown by a traveling-solvent oating-zone method [16]. Single crystals of N a_xC oO $_2$ and C $a_3C_{o_4}O_{o_9}$ were grown by the ux technique [1, 13]. A typical dimension of the samples was 2.0 0.5 0.05 mm 3 . Detailed growth conditions and charge transport were given in the cited references.

Them al conductivity was measured in a closed-cycle refrigerator from 15 to 300 K by the Harman method, where was obtained from temperature dierence induced by applied current I_0 . Figure 2 shows the experimental con guration. This is similar to a four-probe method, but instead of the voltage term inals, two sets of chromel-constantan thermocouple are pasted to detect the temperatures $T_{\rm L}$ and $T_{\rm R}$, and the dierence $T=T_{\rm R}$ $T_{\rm L}$. The sample is hung with current leads (gold wire of 20 mediameter) in vacuum, and is nearly isolated thermally. Then heat absorption/radiation due to the Peltier elect induced by I_0 balances a heat back—

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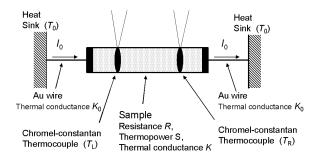


FIG. 2: The sam ple con guration of the Harm an method.

ow across the sample, and in a steady state,

$$STI_0 = K T$$
 (1)

is realized. Thus the therm alconductance K is obtained from S (measured in advance in a dierent run), T and T. In a steady-state method, is obtained from T induced by applied therm alcurrent. Since there is no \constant therm alcurrent source", the measured always has some uncertainty coming from the contact thermal resistance. In contrast, we can use \constant current source" for I_0 in the Harman method, which is free from the contact thermal resistance like a four-term inal method for resistance measurement.

Now we will evaluate the heat loss from current wires. For simplicity, let us assume that the thermocouples are pasted just on the edges of the sample. Then, in a steady-state, the thermal-current balance on the left edge is written as

$$ST_L I_0 = K T + I_0^2 R = 2 + K_0 (T_0 T_L);$$
 (2)

where R is the resistance (including the contact resistance), T_0 is the tem perature at the heat sink, and K $_0$ is the therm all conductance of the wire. Here we take the current direction to give $T_{\rm R} > T_{\rm L}$ for $+ I_0$. Similarly, the therm all current balance on the right edge is written as

$$ST_R I_0 = K T + K_0 (T_R T_0) I_0^2 R = 2$$
: (3)

Then we get

$$I_0^2 R + S I_0 T = 2K_0 (T T_0);$$
 (4)

$$STI_0 = (K + K_0=2) T;$$
 (5)

where T = (T_R + T_L)=2. These equations m ean that K and K $_0$ are simultaneously determined by m easuring S, R, T_L and T_R. In our setup, K $_0$ was estimated to be 2 10 5 W /K by calculating a thermal conductance of a gold wire with a 20- m diameter and a 10-m m long at 300 K. This was consistent with the values obtained through Eq. (4) from the measured values of T_L, T_R and T_0, and was subtracted at every measurement. We evaluated the radiation loss to be 6 10 6 W /K at 300 K through the Stefan-Boltzmann law. Since a typical value of K is 3-5 10 4 W /K, we can safely neglect the contribution of the radiation loss.

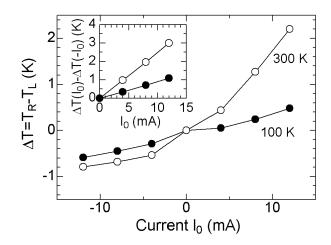


FIG. 3: Tem perature di erence T as a function of applied current ${\rm I}_0$. The inset shows anti-sym metric component of T.

Figure 3 shows the observed T as a function of I $_0$, which contains a quadratic component of I $_0$ due to the Joule heating from the m isalignment of the therm occuples. In order to cancel the quadratic term, we calculated T (I $_0$) T (I $_0$), which is highly proportional to I $_0$, as shown in the inset of Fig. 3. We measured several samples to check the experimental accuracy, and found that the obtained was reproducible within an error bar of less than 10 % for B i $_2$ $_x$ Pb $_x$ Sr $_2$ Co $_2$ O $_y$ and Ca $_3$ Co $_4$ O $_9$, but was rather scattered for Na $_x$ CoO $_2$.

Figure 4 shows the thermal conductivity of various layered cobalt oxides along the CoO2 block. As shown in Fig. 4(a), the data for Na_xCoO_2 are scattered from sample to sample. This is partially because N a_x C oO $_2$ shows a smaller S and weaker Peltier e ect than the other cobalt oxides. Another problem is the high contact resistance owing to the chemically active Na layer. Nonetheless we can extract some common features from is highest among the three cobalt ox-Fig. 4(a): (i) decreases with increasing temperature, indicating a phonon-phonon scattering. (iii) The magnitude and temperature-dependence are quite di erent from those for polycrystalline samples [14, 15]. These features clearly indicate that the disordered Na layer is not very e ective for the reduction, and that the grain boundary scattering seriously reduces of polycrystalline

Figure 4 (b) shows for B i_2 $_x$ P b_x Sr $_2$ C o_2 O $_y$ (x=0,0.4 and 0.6). Unlike N a_x C o_2 0, decreases with decreasing tem perature, and the magnitude is much smaller (particularly for x = 0). These results imply that the phonon mean free path is extremely short in B i_2 $_x$ P b_x Sr $_2$ C o_2 O $_y$. Note that the solid solution between B i and P b increases , as is opposed to usual cases. The P b substitution decreases the excess oxygen [17], and removes the superstructure in the B iO plane [18]. Thus the B iO plane becomes atter for larger x, which would make phonon

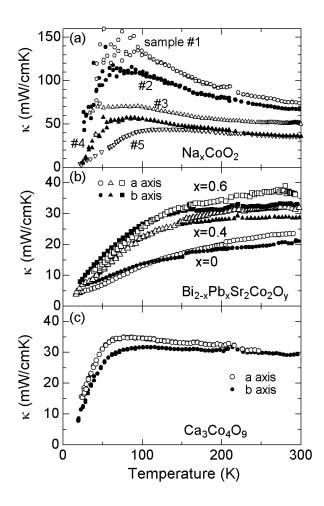


FIG. 4: The in-plane therm al conductivities of the layered cobalt oxides. (a) N a_x C oO $_2$. D i erent m arks represent di erent sam ples (# 1-# 5). (b) B i_2 $_x$ P b_x S r_2 C o_2 O $_y$ (x=0,0.4 and 0.6) and (c) C a_3 C o_4 O $_9$. O pen and lled symbols represent a-and b-axis therm al conductivity, respectively.

m ean free path longer. (The mass dierence between Bi and Pb is so small that point-defect scattering due to Pb is negligible.) A nother notable feature is that a small but nite anisotropy exists between a and baxes. We think that this is due to the mist structure between the hexagonal CoO $_2$ block and the square Bi_Sr_2O $_4$ block. In fact, we found a large in-plane anisotropy in the resistivity and the therm opower of the same crystals [16].

Figure 4(c) shows for Ca $_3$ Co $_4$ O $_9$. As is similar to Biz $_x$ Pb $_x$ Sr $_2$ Co $_2$ O $_y$, a small in-plane anisotropy is observed, which can be attributed to the m is t structure. The magnitude and T dependence are intermediate between those for the previous two systems. Note that a sharp drop below 50 K is clearly observed, which is a hallmark of \clean" crystals. In this sense, the m is t structure does not reduce drastically, as was opposed to the theoretical prediction [19].

Let us compare the present data with the previous

reports. Funahashi and Shikano [12, 13] reported that the in-plane of B i_2 Sr₂Co₂O $_v$ and Ca₃Co₄O $_9$ crystals is 23 and 35 mW/cmK at 300 K, respectively, which is in good agreem ent with our measurement. This evidences the validity of the Harm an method employed here. For Na_xCoO₂, our data are qualitatively consistent with those reported by Fujita et al. [11], but the high NaxCoO2 seems overemphasized in their measurement, presum ably owing to the high therm al resistance at the Na layer. As mentioned above, the Harm an method is free from contact (thermal) resistance, and we believe that the present data are more correct. Very recently, Sales et al. have measured therm alconductivity of singlecrystals of N a_x C oO $_2$, and reported nearly the sam e value as of # 2 [20].

Finally we will comment on the physical meaning of the in-plane in the layered cobalt oxides. The present study has revealed the following features: (a) Based on the Wiedem ann-Franz law, the observed is mainly due to phonon contribution. (b) The lower tends to show the weaker T-dependence. (c) The lower is seen in the material consisting of heavier atoms. One may notice that Ca₃Co₄O₉ consisting of lighter atoms has a lower than Bi_{1:4}Pb_{0:6}Sr₂Co₂O_y. This is perhaps because the Co-O layer in the Ca₂CoO₃ block is highly distorted owing to the mist structure, [21] and the acoustic phonon mode is less dispersive.

Considering these features, we can conclude that the is mainly determined by the phonons in the charge reservoir block (the block other than the CoO_2 block). This implies that a nano-block integration concept works well in the layered cobalt oxides, where a nano-block for the electronic part and a nano-block for the therm alpart can be independently tuned or designed. This is a similar situation to the material design for hightem perature superconductors, where a superconductor can be synthesized by combining proper charge reservoirs with the superconducting CuO2 plane [22]. As a result, we can modify chemical properties, anisotropy and/orunit cellvolum e, rem aining the superconductivity intact. Sim ilarly, we can modify the therm al conductivity by changing the charge reservoir without degrading the large therm opower in the CoO2 block in the layered cobalt oxides.

In sum m ary, we have m easured the in-plane therm all conductivity of the therm celectric layered cobalt oxides N a_x C oO $_2$, B i_2 $_x$ P b_x S r_2 C o $_2$ O $_y$ and C a_3 C o $_4$ O $_9$, and have found that the charge reservoir block dom inates the thermal conduction. By changing the charge reservoir layer, we can m odify the thermal properties, remaining the electronic properties in the C oO $_2$ block unperturbed.

The authors would like to thank M . Shikano for helpful suggestion for crystal growth of $Ca_3Co_4O_9$. They also appreciate R . K itawaki, W . K obayashi and K . Takahata for collaboration.

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